

MDL-H-2200/1~450mW

## INFRARED DIODE LASER AT 2200nm





Diode infrared laser module at 2200nm is made features of ultra compact, long lifetime, low cost and easy operating, which is used in measurement, communication, spectrum analysis, etc.



### SPECIFICATIONS

Wavelength (nm)	2200±10		
Output power (mW)	>1, 50, 100, ... , 450		
Transverse mode	Near TE <sub>00</sub>		
Operating mode	CW		
Power stability (rms, over 4 hours)	<1%, <3%, <5%		
Warm-up time (minutes)	<5		
M <sup>2</sup> factor	<20		
Beam divergence, full angle (mrad)	<5.0		
Beam diameter at the aperture (mm)	10~12		
Beam height from base plate (mm)	29		
Polarization ratio	>50:1		
Pointing stability after warm-up (mrad)	<0.05		
Operating temperature (°C)	10~35		
Power supply (90-264VAC)	PSU-H-LED	PSU-H-FDA	PSU-H-OEM
Modulation option	TTL/Analog 1Hz-5KHz, 1Hz-10KHz, 1Hz-30KHz, and TTL on/off		
Expected lifetime (hours)	10000		
Warranty period	1 year		



MxL-H-2200	PSU-H-LED	PSU-H-FDA	PSU-H-OEM
 153(L)×77(W)×60(H) mm <sup>3</sup> , 0.9 kg	 268 (L) ×145(W) ×106 (H) mm <sup>3</sup> , 2.6 kg	 238 (L) ×146(W) ×102 (H) mm <sup>3</sup> , 2.3 kg	 238 (L) ×146(W) ×94 (H) mm <sup>3</sup> , 2.2 kg
